

## **DESCRIPTION:**

The sidac is a silicon bilateral voltage triggered switch with greater power-handling capabilities than standard diacs. Upon application of a voltage exceeding the sidac breakover voltage point, the sidac switches on through a negative resistance region to a low on-state voltage. Conduction continues until the current is interrupted or drops below the minimum holding current of the device.

### **APPLICATIONS:**

- ♦ High-voltage lamp ignitors
- ♦ Natural gas ignitors
- ♦ Gas oil ignitors
- ♦ High-voltage power supplies
- ♦ Xenon ignitors
- ♦ Overvoltage protector
- ♦ Pulse generators
- ♦ Fluorescent lighting ignitorsHID lighting ignitors

## FEATURES:

- ♦ Excellent capability of absorbing transient surge
- ♦ Quick response to surge voltage (ns Level)
- ♦ Glass-passivated junctions
- ♦ High voltage lcmp ignitors

#### **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C, RH=45%-75%, unless otherwise noted)

| Parameter  | Symbol           | Value       | Unit |
|--|------------------|-------------|------|
| Storage temperature range  | T <sub>stg</sub> | -40 to +125 | °C   |
| Operating junction temperature range   | Tj               | -40 to +125 | °C   |
| On-state RMS Current   | Ι <sub>Τ</sub>   | 1           | А    |
| Maximum surge on-state current<br>non-repetitive one cycle peak value (50Hz) | I <sub>TSM</sub> | 16.7        | А    |
| Critical rate-of-rise of on-state current                                    | di⊤/dt           | 80          | А    |



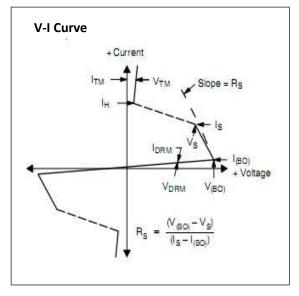
Rev.1.0

Symbol



# ELECTRICAL CHARACTERISTICS (T\_A=25 $^\circ\mathrm{C}$ )

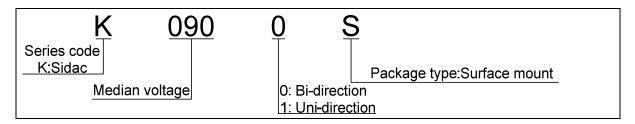
| Symbol           | Parameter                      |  |  |  |
|------------------|--------------------------------|--|--|--|
| V <sub>DRM</sub> | Peak off-state voltage         |  |  |  |
| I <sub>DRM</sub> | Off-state current              |  |  |  |
| Vs               | Switching voltage              |  |  |  |
| I <sub>S</sub>   | Switching current              |  |  |  |
| Rs               | Switching resistance           |  |  |  |
| VT               | On-state voltage               |  |  |  |
| I <sub>H</sub>   | I <sub>H</sub> Holding current |  |  |  |
| V <sub>BO</sub>  | Breakover Voltage              |  |  |  |
| I <sub>BO</sub>  | Breakover current              |  |  |  |



### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub>=25°C, continued)

|                | I <sub>DRM</sub> @ | VDRM | V   | во  | I <sub>BO</sub> | V <sub>T</sub> @ I <sub>T=</sub> 1A | I <sub>H</sub> | Rs  |         |
|----------------|--------------------|------|-----|-----|-----------------|-------------------------------------|----------------|-----|---------|
| Part<br>Number | μA                 | V    | ١   | /   | uA              | V                                   | mA             | kΩ  | Marking |
|                | max                | min  | min | max | max             | max                                 | min            | min |         |
| K0900S         | 1                  | 70   | 80  | 97  | 50              | 2                                   | 10             | 0.1 | K09S    |
| K1050S         | 1                  | 90   | 95  | 113 | 50              | 2                                   | 10             | 0.1 | K10S    |
| K1200S         | 1                  | 100  | 110 | 125 | 50              | 2                                   | 10             | 0.1 | K12S    |
| K1300S         | 1                  | 110  | 120 | 138 | 50              | 2                                   | 10             | 0.1 | K13S    |
| K1400S         | 1                  | 120  | 130 | 146 | 50              | 2                                   | 10             | 0.1 | K14S    |
| K1500S         | 1                  | 130  | 140 | 170 | 50              | 2                                   | 10             | 0.1 | K15S    |
| K1800S         | 1                  | 160  | 170 | 195 | 50              | 2                                   | 10             | 0.1 | K18S    |
| K2000S         | 1                  | 180  | 190 | 215 | 50              | 2                                   | 10             | 0.1 | K20S    |
| K2200S         | 1                  | 190  | 205 | 230 | 50              | 2                                   | 10             | 0.1 | K22S    |
| K2400S         | 1                  | 200  | 220 | 250 | 50              | 2                                   | 10             | 0.1 | K24S    |
| K2600S         | 1                  | 220  | 240 | 270 | 50              | 2                                   | 10             | 0.1 | K26S    |

## **ORDERING INFORMATION**



#### MARKING



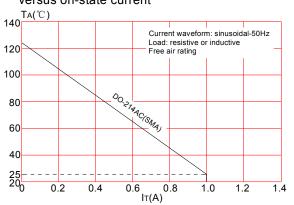
K09S:Device Marking Code 1409: In ninth week, 2014

### SOLDERING PARAMETERS

| Reflow Condition  |   | Pb-Free assembly<br>(see FIG.2) |  |  |
|---|---|---------------------------------|--|--|
|   | -Temperature Min (T <sub>s(min)</sub> )   | +150℃                           |  |  |
| Pre Heat  | -Temperature Max(T <sub>s(max)</sub> )    | +200℃                           |  |  |
|   | -Time (Min to Max) (ts)                   | 60-180 secs.                    |  |  |
| Average ramp  | up rate (Liquid us Temp $(T_L)$ to peak)  | 3℃/sec. Max                     |  |  |
| $T_{s(max)}$ to $T_L$ - R   | amp-up Rate                               | 3℃/sec. Max                     |  |  |
| Reflow  | -Temperature(T <sub>L</sub> ) (Liquid us) | +217℃                           |  |  |
|   | -Temperature(t <sub>L</sub> )             | 60-150 secs.                    |  |  |
| Peak Temp (T <sub>p</sub> )   |   | <b>+260(+0/-5)</b> ℃            |  |  |
| Time within 5 $^\circ \!\!\!\!\!^{\rm C}$ of actual Peak Temp (t_p) |   | 8-15 secs.                      |  |  |
| Ramp-down Rate  |   | 6℃/sec. Max                     |  |  |
| Time 25 $^\circ C$ to Peak Temp (T <sub>P</sub> )                   |   | 8 min. Max                      |  |  |
| Do not exceed   |   | <b>+260</b> ℃                   |  |  |



**FIG.1:** Maximum allowable ambient temperature versus on-state current



**FIG.3:** Normalized Vs change vs. junction temperature

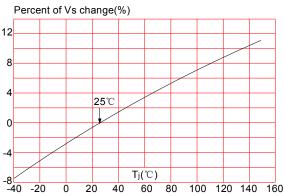
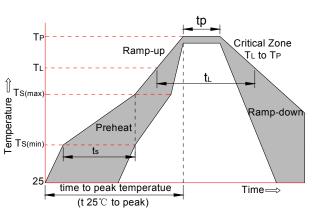
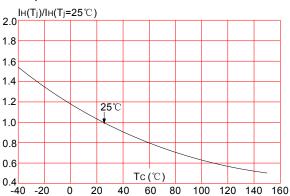


FIG.2: Reflow condition



**FIG.4:** Normalized DC holding current vs. case temperature



#### TAPE AND REEL SPECIFICATION

| PACKAGE     | REEL<br>(PCS) | PER CARTON<br>(PCS) | REEL DIAMETERS<br>(mm) |
|-------------|---------------|---------------------|------------------------|
| DO214AC/SMA | 5,000         | 80,000              | 330                    |
| DO214AA/SMB | 3,000         | 48,000              | 330                    |

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